

## (12) United States Patent

Segawa et al.

### (54) SEMICONDUCTOR DEVICE WHICH REDUCES THE MINIMUM DISTANCE REQUIREMENTS BETWEEN ACTIVE AREAS

- Inventors: Mizuki Segawa; Isao Miyanaga; Toshiki Yabu; Takashi Nakabayashi; Takashi Uehara; Kyoji Yamashita; Takaaki Ukeda; Masatoshi Arai; Takayuki Yamada; Michikazu Matsumoto, all of Osaka (JP)
- (73) Assignee: Matsushita Electric Industrial Co., Ltd., Osaka (JP)
- (\*) Notice: This patent issued on a continued prosecution application filed under 37 CFR 1.53(d), and is subject to the twenty year patent term provisions of 35 U.S.C. 154(a)(2).

Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 0 days.

- (21) Appl. No.: 08/685,726
- (22) Filed: Jul. 24, 1996

### (30) Foreign Application Priority Data

Jul. 27, 1995	(JP)	 7-192181
Dec. 19, 1995	(JP)	 7-330112

- (51) Int. Cl.<sup>7</sup> ...... H01L 29/167; H01L 29/00;
- H01L 21/331; H01L 21/76
- (52) U.S. Cl. ..... 257/510; 257/304; 257/774;
- 438/359; 438/424

   (58) Field of Search

   257/304, 510,
- 257/774, 311; 438/359, 424

### (56) **References Cited**

### U.S. PATENT DOCUMENTS

4,578,128	*	3/1986	Mundt et al 148/191
5,177,028		1/1993	Manning 437/41
5,196,910	*	3/1993	Moriuchi et al 257/510

(10) Patent No.: US 6,281,562 B1
(45) Date of Patent: \*Aug. 28, 2001

5,286,674		2/1994	Roth et al 437/190
5.319.235	*		Kihara et al 257/370
5,397,910		3/1995	Ishimaru 257/387
5,401,673		3/1995	Urayama 437/187
5,413,961		5/1995	Kim 437/195
5,433,794	*	7/1995	Fazan et al 148/33.3
5,497,016	*	3/1996	Koh 257/306
5,521,422	*	5/1996	Mandelman et al 257/510
5,561,311	*	10/1996	Hamamoto et al 257/309
5,777,370	*	7/1998	Omid-Zohoor et al 257/374
5,804,862	*	9/1998	Matumoto 257/396
6.022.781	*	2/2000	Noble, Jr. et al 438/296

### FOREIGN PATENT DOCUMENTS

0 243 988		11/1987	(EP) .
0 513 639		11/1992	(EP).
4-68564	*	3/1992	(JP) 257/510
6-163843		6/1994	(JP) .

\* cited by examiner

Primary Examiner—Olik Chaudhuri Assistant Examiner—Howard Weiss

(74) Attorney, Agent, or Firm-McDermott, Will & Emery

### (57) ABSTRACT

An isolation which is higher in a stepwise manner than an active area of a silicon substrate is formed. On the active area, an FET including a gate oxide film, a gate electrode, a gate protection film, sidewalls and the like is formed. An insulating film is deposited on the entire top surface of the substrate, and a resist film for exposing an area stretching over the active area, a part of the isolation and the gate protection film is formed on the insulating film. There is no need to provide an alignment margin for avoiding interference with the isolation and the like to a region where a connection hole is formed. Since the isolation is higher in a stepwise manner than the active area, the isolation is prevented from being removed by over-etch in the formation of a connection hole to come in contact with a portion where an impurity concentration is low in the active area. In this manner, the integration of a semiconductor device can be improved and an area occupied by the semiconductor device can be decreased without causing degradation of junction voltage resistance and increase of a junction leakage current in the semiconductor device.

### 12 Claims, 21 Drawing Sheets

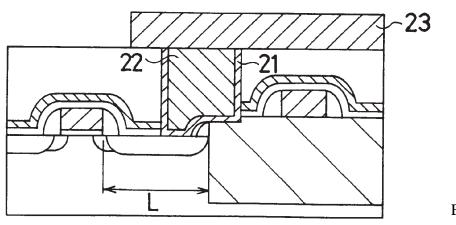
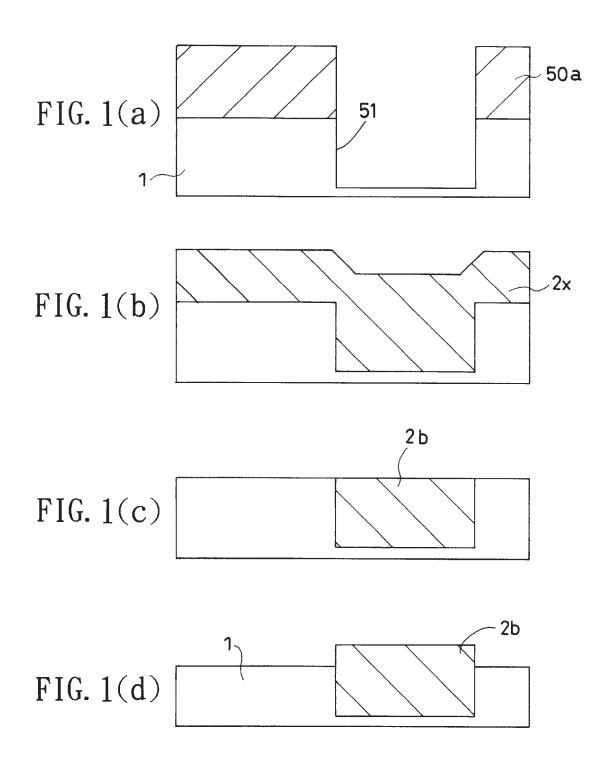
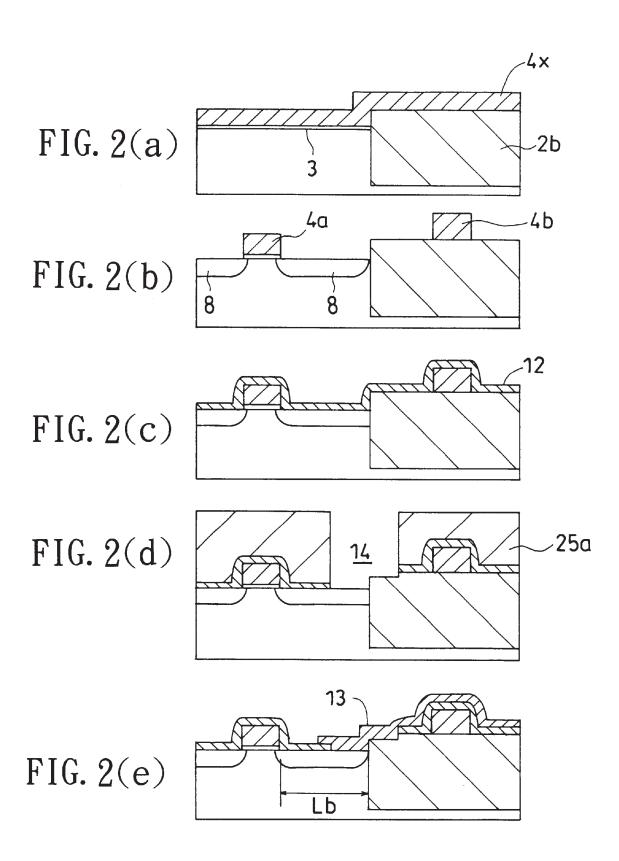


Exhibit 2061

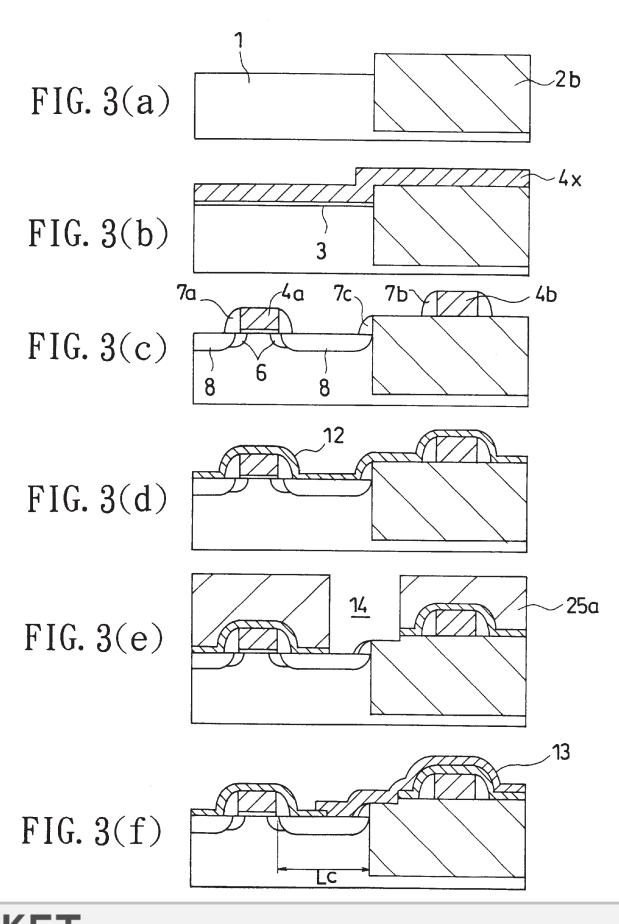
Find authenticated court documents without watermarks at docketalarm.com.



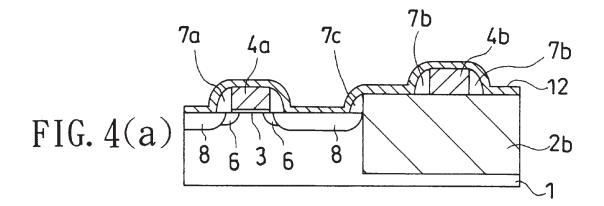
Α

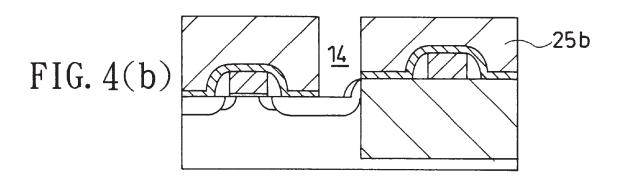


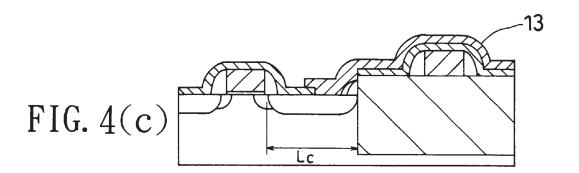
Δ



R Find authenticated court documents without watermarks at docketalarm.com.







**DOCKET A L A R M** Find authenticated court documents without watermarks at <u>docketalarm.com</u>.

## DOCKET A L A R M



# Explore Litigation Insights

Docket Alarm provides insights to develop a more informed litigation strategy and the peace of mind of knowing you're on top of things.

## **Real-Time Litigation Alerts**



Keep your litigation team up-to-date with **real-time alerts** and advanced team management tools built for the enterprise, all while greatly reducing PACER spend.

Our comprehensive service means we can handle Federal, State, and Administrative courts across the country.

## **Advanced Docket Research**



With over 230 million records, Docket Alarm's cloud-native docket research platform finds what other services can't. Coverage includes Federal, State, plus PTAB, TTAB, ITC and NLRB decisions, all in one place.

Identify arguments that have been successful in the past with full text, pinpoint searching. Link to case law cited within any court document via Fastcase.

## **Analytics At Your Fingertips**



Learn what happened the last time a particular judge, opposing counsel or company faced cases similar to yours.

Advanced out-of-the-box PTAB and TTAB analytics are always at your fingertips.

## API

Docket Alarm offers a powerful API (application programming interface) to developers that want to integrate case filings into their apps.

## LAW FIRMS

Build custom dashboards for your attorneys and clients with live data direct from the court.

Automate many repetitive legal tasks like conflict checks, document management, and marketing.

## FINANCIAL INSTITUTIONS

Litigation and bankruptcy checks for companies and debtors.

## E-DISCOVERY AND LEGAL VENDORS

Sync your system to PACER to automate legal marketing.